



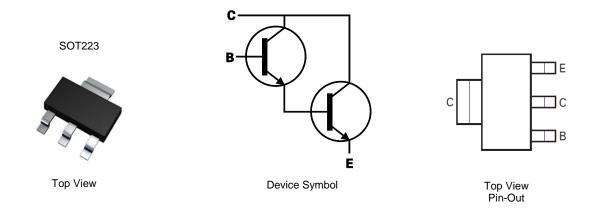
140V NPN DARLINGTON TRANSISTOR IN SOT223

Features

- BV_{CEO} > 140V
- BV_{CBO} > 160V
- I_C = 2A High Continuous Current
- NPN Darlington With Gain > 10k
- Guaranteed h_{FE} Specified up to 1A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (FZT600BQ)

Mechanical Data

- Case: SOT223 (Type DN)
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT600TA	AEC-Q101	FZT600	7	12	1000
FZT600BTA	AEC-Q101	FZT600B	7	12	1000

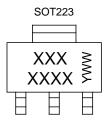
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, see http://www.diodes.com/products/packages.html.

Marking Information

Notes:



XXX XXXX = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 8= 2018) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	160	V
Collector-Emitter Voltage	V _{CEO}	140	V
Emitter-Base Voltage	V _{EBO}	10	V
Continuous Collector Current	lc	2	A
Peak Pulse Current	I _{CM}	4	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Power Dissipation	(Note 6)	Р	2.0	W	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	R _θ JA	62.5		
mermar Resistance, Junction to Ambient	(Note 7)		78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	R _{ƏJL}	12.9		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	2000	V	2
Electrostatic Discharge—Machine Model	ESD MM	200	V	В

5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. 6. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 6, except the device is mounted on 25mm × 25mm 1oz copper.

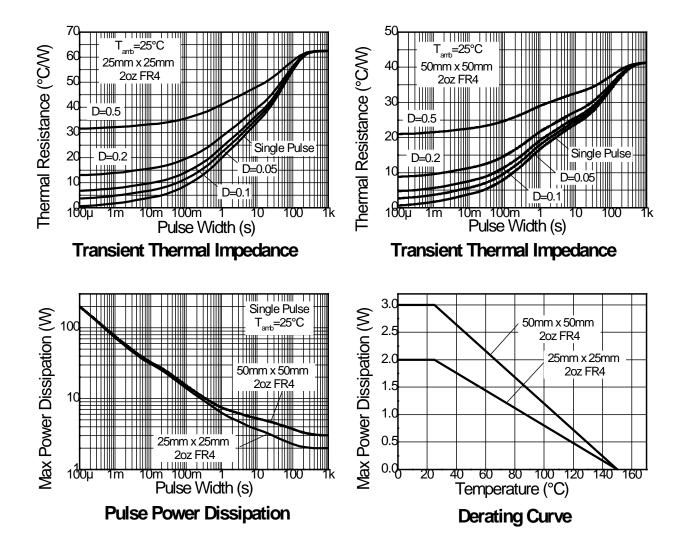
8. Same as Note 6, except the device is mounted on minimum recommended pad layout.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





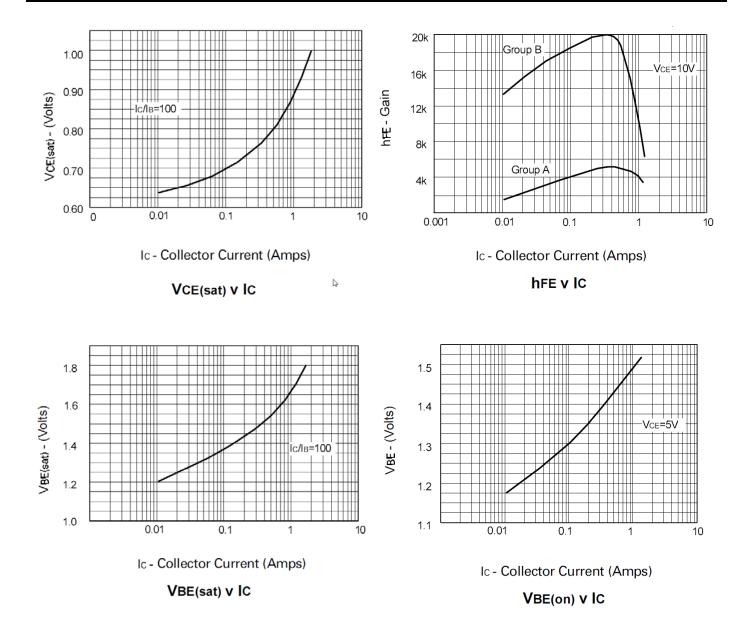
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV CBO	160	-	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	140			V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	10	-	_	V	I _E = 100μA
Collector-Base Cut-Off Current	I _{CBO}	_	_	0.01 10	μΑ μΑ	V _{CB} = 140V V _{CB} = 140V, T _A = +100°C
Collector-Emitter Cut-Off Current	ICES	-	_	10	μA	V _{CES} = 140V
Emitter Cut-Off Current	I _{EBO}	-	_	0.1	μA	V _{EB} = 8V
Group A (FZT600) DC Current Gain (Note 12)	h _{FE}	1000 2000 1000		 100,000 	_	$\begin{split} I_{C} &= 50 \text{mA}, V_{CE} = 10 \text{V} \\ I_{C} &= 500 \text{mA}, V_{CE} = 10 \text{V} \\ I_{C} &= 1\text{A}, V_{CE} = 10 \text{V} \end{split}$
Group B (FZT600B)	ΠΕΕ	5000 10,000 5000	10,000 20,000 10,000	 100,000 		$\begin{split} I_{C} &= 50 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 500 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 1\text{A}, \ V_{CE} = 10 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(sat)}		0.75 0.85	1.1 1.2	V	$I_C = 500$ mA, $I_B = 5$ mA $I_C = 1$ A, $I_B = 10$ mA
Base-Emitter Saturation Voltage (Note 12)	V _{BE(sat)}	_	1.7	1.9	V	$I_{C} = 1A, I_{B} = 10mA$
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(on)}	_	1.5	1.7	V	$I_C = 1A, V_{CE} = 5V$
Output Capacitance (Note 12)	C _{obo}	_	10	15	pF	$V_{CB} = 10V, f = 1MHz$
Current Gain-Bandwidth Product (Note 12)	f⊤	150	250	_	MHz	$V_{CE} = 10V, I_C = 100mA,$ f=20MHz
Turn-On Time	t _{on}	—	0.75	_	μs	$V_{CC} = 10V, I_{C} = 500mA$
Turn-Off Time	t _{off}	_	2.20	_	μs	$I_{B1} = -I_{B2} = 0.5 \text{mA}$

Note: 12. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%.



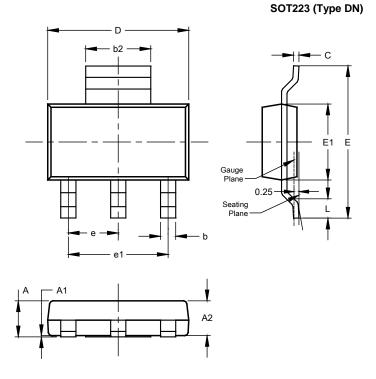
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

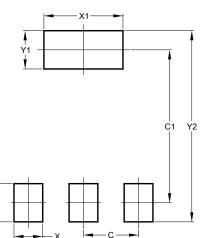
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α	—	1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70	—		
Е	6.70	7.30			
E1	3.30	3.70	—		
е	I		2.30		
e1		-	4.60		
L	0.85	_			
All [All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: 13. For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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